

## Model VPO-300

### Vacuum Process Oven up to 300 mm dia. or 300 mm x 300 mm substrate size



Technical and design changes reserved

- For substrate size up to 300mm x 300mm
- Ramp up rate up to 40 K/sec.  
Ramp down rate up to 200 K/min.
- Control **SIMATIC®** with 7" touch panel
- Vacuum up to  $10^{-3}$  hPa  
(optional up to  $10^{-6}$  hPa)
- Process gas line with MFC for  $N_2$
- Temperature up to 1000 °C

## FEATURE

- Precise ramp up and fast ramp down rates
- Up to 4 gas lines
- Heated by 48 IR Lamps
- 50 programs with 50 steps each
- Top and bottom heating (selection by Software)
- Small foot print

## APPLICATION

- Implantation/Contact Annealing
- RTP, RTA, RTO, RTN
- Operation with inert gases, Oxygen, Hydrogen, Forming gas
- SiAu, SiAl, SiMo Alloying
- Low k dielectrics
- Crystallization & densification
- Si-Solar Wafer Cells on glass by Si-Wafer bonding

## Model VPO-300

- Vacuum Process Oven
- Programmable temperature profiles
- Record of process data
- Process in different gas atmospheres
- Perfect lab tool due to small dimensions and weight



### APPLICATION

The **VPO-300** Reflow Solder System is an excellent tool for various semiconductor up to 300mm wafer or 300 mm x 300 mm substrate size.

Some examples for applications: Laboratory furnace for all kind of developers implementing and researching new processes, prototype research, environmental research purposes and for small pre-series or series.

### PROCESS GASES

The VPO-300 can be used with standard process gases, like Nitrogen, Oxygen, Forming Gas. The chamber is sealed and can easily be cleaned.

### FLOW METER

One gas line with Mass Flow Controller (MFC) for Nitrogen (5 nlm = norm liter per minute) is default, three more gas lines (**Option: MFC**) are possible.

### VACUUM

The system is vacuum capable of up to  $10^{-3}$  hPa (optionally up to  $10^{-6}$  hPa)

### HEATING

The maximal achievable temperature is 1000 °C. Key features are precisely controlled fast ramp-up (40 K/sec) and excellent ramp-down rates (depend on temperature and loading).

### TEMPERATURE DISTRIBUTION

The VPO-300 allows an excellent temperature distribution and homogeneity. Optionally a graphite susceptor can be inserted on the quartz bottom plate.

### PROGRAMMING

The VPO-300 is controlled by SIMATIC SPS controller. A 7" touch panel allows a very comfortable programming and control of the process. There can be saved up to 50 programs with 50 steps each (unlimited programs can be down- and uploaded from an external data storage).

### PROCESS CONTROL

The software allows the permanent monitoring, read-out and analysis of

- >temperature
- >process gas flow
- >cooling water level status
- >pressure value and status

### COOLING

The cooling of the parts in the quartz chamber is realized by Nitrogen gas which will be led through the chamber. For chamber cooling we recommend a closed loop water cooling system.

(Accessories: WC III or WC IV)

### OTHERS

An interlock function as well as an Emergency-OFF-Button (EMO) are default.

### SPECIAL

This oven can also be integrated into a production line. The chamber open/close is realized by push button operation. Optionally we offer the adaption into a fully automatic open/close system is possible (remote control by interface and robotics system).

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### SPECIFICATION

Max. part size	300 mm dia. or 300 mm x 300 mm
Chamber material	Aluminium chamber (chamber area: 350 mm x 350 mm) inclusive quartz glass bottom plate
Chamber height	50 mm (optional: 120 mm)
Vacuum capability	Up to $10^{-3}$ hPa (optional up to $10^{-6}$ hPa)
Temperature max.	1000 °C (for max. 10 sec)
Temp. uniformity	$\leq 1\%$ of set temperature (on a 200 mm wafer) (e.g. +/- 3K @ 300 °C)
Heating	Bottom Heating: 2 x 12 IR lamps cross aligned (18 kW) Top Heating: 2 x 12 IR lamps cross aligned (18 kW)
Ramp up rate	40 K/sec
Ramp down rate	T= 1000°C > 400°C: 200 K/min, T= 400°C > 100°C: 30 /min
Flow Controller	One Mass Flow Controller for 5 nlm (=norm liter per minute) as default, up to 3 more MFCs are available as option
Controller	SIMATIC® 50 programs with 50 steps each
Chamber cooling	By external water cooling system
Substrate Cooling	By Nitrogen Gas

### TECHNICAL DATA

Dimension oven	505 mm x 504 mm x 830 mm (W x D x H)
Weight	100 kg (estimated)
Electrical connection	2 x [400/230V, 21 kW]

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### OPTIONS

VPO-CAB	Floor model with cabinet and integrated Universal Heat Exchanger (UHE)
VPO-MFC	Additional gas line with Mass Flow controller (total: max 4 gas lines)
VPO-EH	Chamber height 120mm (instead of 50mm) with viewing window (60mm diameter)
VPO-SS	Chamber made of stainless steel (VA 1.4305) polished, instead of aluminium 50mm
VPO-GP	Graphite Plate or Susceptor
VPO-TC	Additional thermocouple to measure on device (plugged in chamber) (max. 4 pcs)
VPO-QP	Quartz glass plate (5 mm thickness) for sealing the top lamp field
VPO-SI	Serial interface between VPO system and external PC
VPO-RC	Remote control of top cover opening and closing
VAC I	Basic Vacuum up to 3 hPa, Vacuum sensor, vacuum valve excl. pump
VAC II	Comfort Vacuum up to $10^{-3}$ hPa, Pirani Sensor, vacuum valve, excl.pump

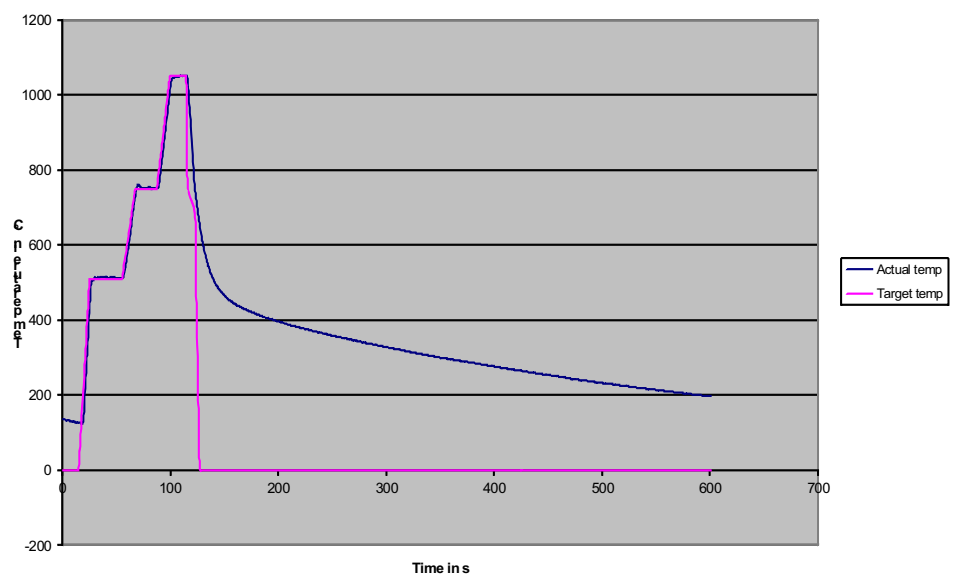
### ACCESSORIES

We offer a lot of different kind of closed loop water coolers and different pumps from e.g. Pfeiffer, Edwards, Leybold, Agilent. We recommend the correct configuration for your system.



VSS-300 with cabinet

VPO-1000-300 with 200 mm Si-Wafer Heating-Cooling profile



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